



# DATA SHEET

## ER1600CT~ER1604CT

### SUPERFAST RECOVERY RECTIFIER

**VOLTAGE** 50 to 400 Volts **CURRENT** 16.0 Amperes

TO-220AB

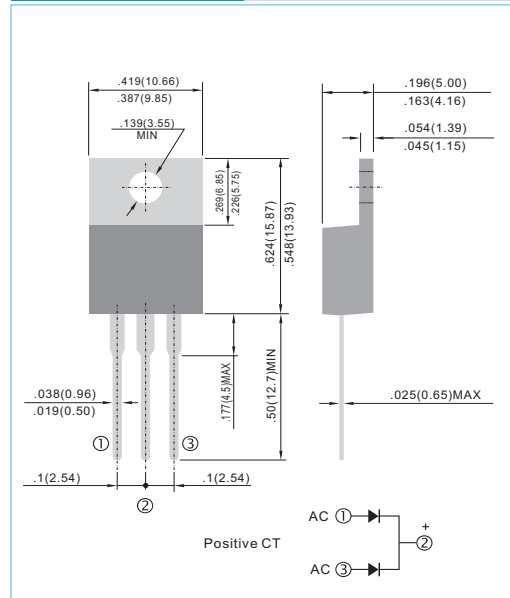
Unit : inch (mm)

#### FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O. Flame Retardant Epoxy Molding Compound.
- Exceeds environmental standards of MIL-S-19500/228
- Low power loss, high efficiency.
- Low forward voltage, high current capability
- High surge capacity.
- Super fast recovery times, high voltage.
- Epitaxial chip construction.
- Both normal and Pb free product are available :  
Normal : 80~95% Sn, 5~20% Pb  
Pb free: 98.5% Sn above

#### MECHANICAL DATA

Case: TO-220AB Molded plastic  
Terminals: Lead solderable per MIL-STD-202, Method 208  
Polarity: As marked.  
Standard packaging: Any  
Weight: 0.08 ounces, 2.24grams.



#### MAXIMUM RATING AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

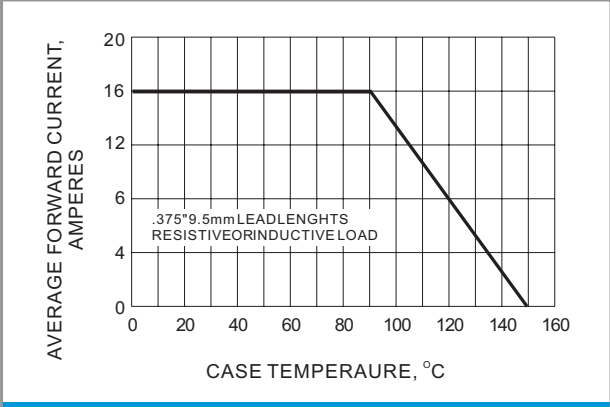
PARAMETER	SYMBOL	ER1600 CT	ER1601 CT	ER1601A CT	ER1602 CT	ER1603 CT	ER1604 CT	UNITS
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	V
Maximum RMS Voltage	$V_{RMS}$	35	70	105	140	210	280	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	V
Maximum Average Forward Current .375" (9.5mm) lead length at $T_c = 90^\circ C$	$I_{AV}$	16.0						A
Peak Forward Surge Current, 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	$I_{FSM}$	125						A
Maximum Forward Voltage at 8A	$V_F$	0.95				1.30		V
Maximum DC Reverse Current at $T_A = 25^\circ C$ Rated DC Blocking Voltage $T_A = 100^\circ C$	$I_R$	10 500						$\mu A$
Maximum Reverse Recovery Time (Note 2)	$T_{RR}$	35				50		ns
Typical Junction capacitance (Note 1)	$C_J$	62						pF
Maximum Thermal Resistance	$R_{\theta JC}$	3.0						$^\circ C / W$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-50 TO +150						$^\circ C$

#### NOTES:

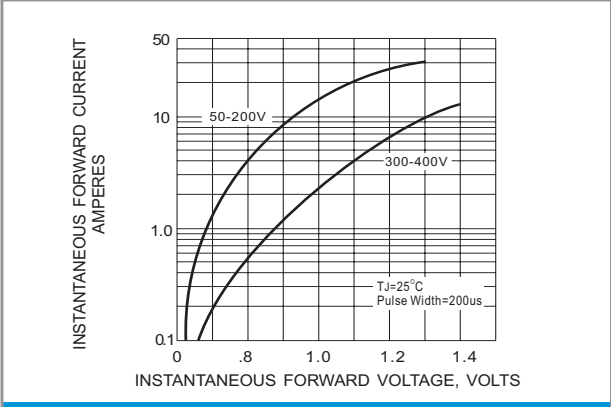
1. Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
2. Reverse Recovery Test Conditions:  $I_F = .5A$ ,  $I_R = 1A$ ,  $I_{rr} = .25A$ .
3. Both Bonding and Chip structure are available.



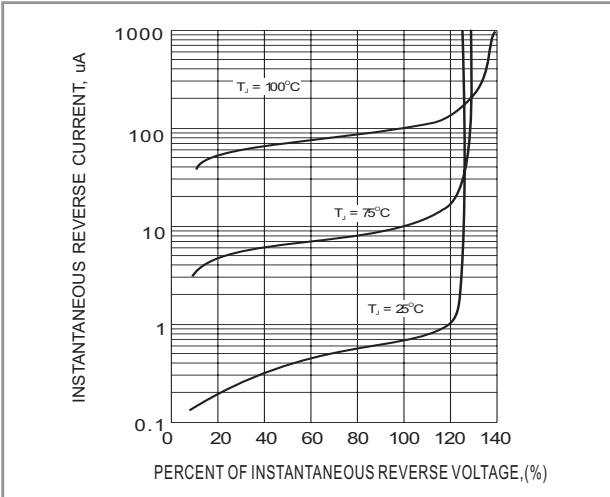
**RATING AND CHARACTERISTIC CURVES**



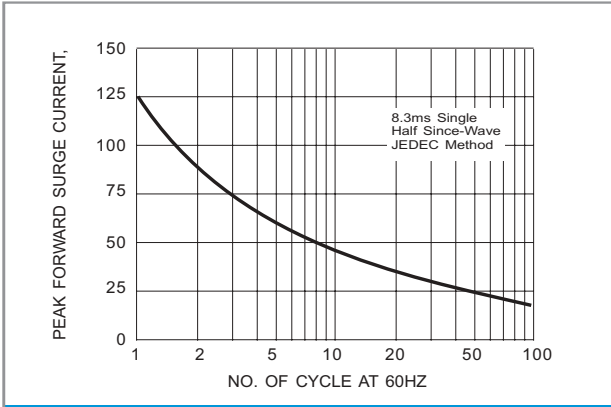
**Fig.1- FORWARD CURRENT DERATING CURVE**



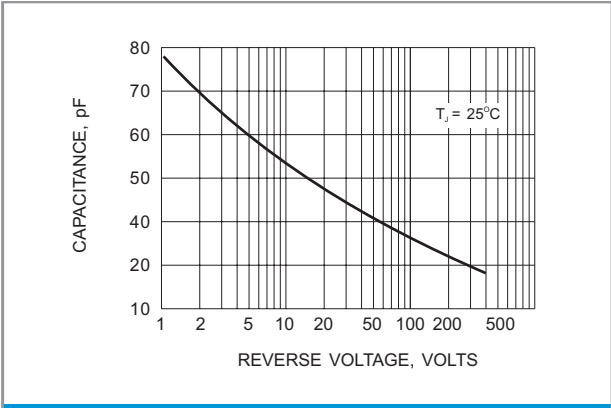
**Fig.2- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTIC**



**Fig.3- TYPICAL REVERSE CHARACTERISTIC**



**Fig.4- MAXIMUM NON - REPETITIVE SURGE CURRENT**



**Fig.5- TYPICAL JUNCTION CAPACITANCE**